NSN 5961-01-324-1160

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-324-1160 **Inclosure Material:** Plastic **Overall Length:** 0.625 inches **Terminal Length:** 0.580 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ac **Mounting Method:** Terminal and unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak reverse voltage and 200.0 working peak reverse voltage and 200.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 15.00 amperes forward current, average absolute and 30.00 amperes source cutoff current absolute and 150.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**